

# MC74HC4067A

## Quad Analog Switch/ Multiplexer/Demultiplexer

### High-Performance Silicon-Gate CMOS

The MC74HC4067A utilizes silicon-gate CMOS technology to achieve fast propagation delays, low ON resistances, and low OFF-channel leakage current. This bilateral switch/multiplexer/demultiplexer controls analog and digital voltages that may vary across the full power-supply range (from  $V_{CC}$  to GND).

The ON/OFF control inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs. For analog switches with voltage-level translators, see the HC4316A.

#### Features

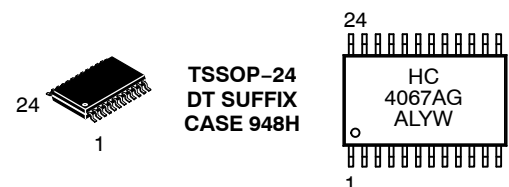
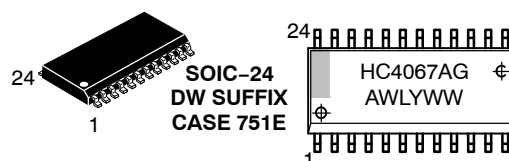
- Fast Switching and Propagation Speeds
- High ON/OFF Output Voltage Ratio
- Low Crosstalk Between Switches
- Diode Protection on All Inputs/Outputs
- Wide Power-Supply Voltage Range ( $V_{CC} - GND$ ) = 2.0 to 6.0 V
- Analog Input Voltage Range ( $V_{CC} - GND$ ) = 0 to 6.0 V
- Improved Linearity and Lower ON Resistance over Input Voltage
- Low Noise
- These are Pb-Free Devices



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#### MARKING DIAGRAMS



A = Assembly Location  
L, WL = Wafer Lot  
Y, YY = Year  
W, WW = Work Week  
G = Pb-Free Package

(Note: Microdot may be in either location)

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

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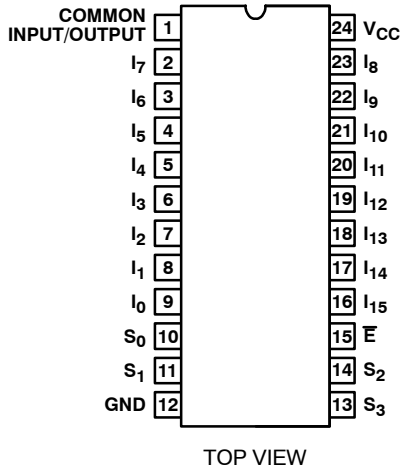


Figure 1. Pin Assignment

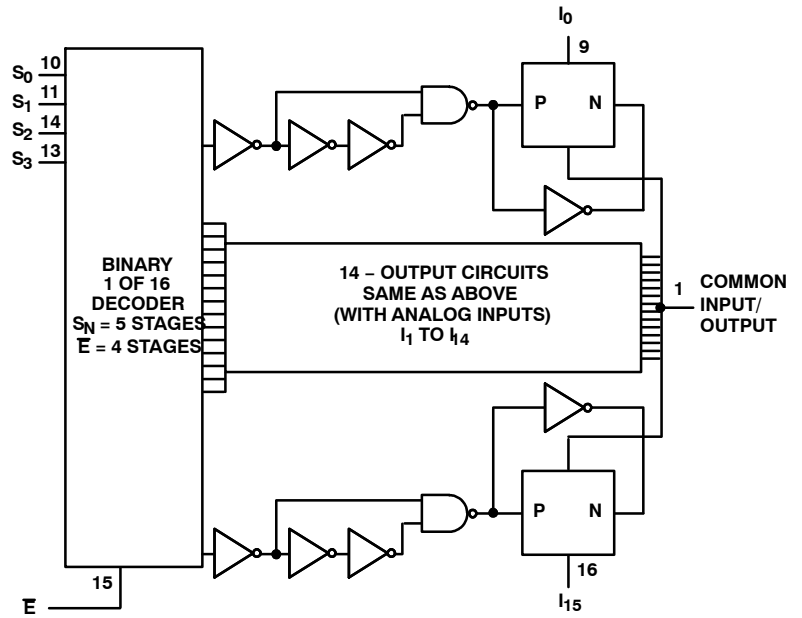


Figure 2. Function Diagram

## TRUTH TABLE

S0	S1	S2	S3	$\bar{E}$	SELECTED CHANNEL
X	X	X	X	1	None
0	0	0	0	0	0
1	0	0	0	0	1
0	1	0	0	0	2
1	1	0	0	0	3
0	0	1	0	0	4
1	0	1	0	0	5
0	1	1	0	0	6
1	1	1	0	0	7
0	0	0	1	0	8
1	0	0	1	0	9
0	1	0	1	0	10
1	1	0	1	0	11
0	0	1	1	0	12
1	0	1	1	0	13
0	1	1	1	0	14
1	1	1	1	0	15

H= High Level  
 L= Low Level  
 X= Don't Care

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## MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V
V <sub>IS</sub>	Analog Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
V <sub>IN</sub>	Digital Input Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input Clamping Current	V <sub>IN</sub> < -0.5 V or V <sub>IN</sub> > V <sub>CC</sub> + 0.5 V	±20 mA
I <sub>SK</sub>	Switch Input Clamping Current	V <sub>IS</sub> < -0.5 V or V <sub>IS</sub> > V <sub>CC</sub> + 0.5 V	±20 mA
I <sub>IS</sub>	DC Switch Current	±25	mA
I <sub>O</sub>	DC Output Source / Sink Current	±25	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C
T <sub>J</sub>	Junction Temperature under Bias	+150	°C
θ <sub>JA</sub>	Thermal Resistance	SOIC TSSOP	97 148 °C/W
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	SOIC TSSOP	500 450 mW
MSL	Moisture Sensitivity	Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 30% – 35%	UL-94-VO (0.125 in)
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 1) Machine Model (Note 2)	>3000 >200 V
I <sub>Latchup</sub>	Latchup Performance	Above V <sub>CC</sub> and Below GND at 85°C (Note 3)	±100 mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Tested to EIA/JESD22-A114-A.
2. Tested to EIA/JESD22-A115-A.
3. Tested to EIA/JESD78.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V <sub>IS</sub>	Analog Input Voltage (Referenced to GND)	GND	V <sub>CC</sub>	V
V <sub>in</sub>	Digital Input Voltage (Referenced to GND)	GND	V <sub>CC</sub>	V
V <sub>IO*</sub>	Static or Dynamic Voltage Across Switch	-	1.2	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Rate (Digital Inputs)	V <sub>CC</sub> = 2.0 V V <sub>CC</sub> = 3.0 V V <sub>CC</sub> = 4.5 V V <sub>CC</sub> = 6.0 V	0 0 0 0	1000 600 500 400 ns

\*For voltage drops across the switch greater than 1.2 V (switch on), excessive V<sub>CC</sub> current may be drawn; i.e., the current out of the switch may contain both V<sub>CC</sub> and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

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## DC ELECTRICAL CHARACTERISTIC Digital Section (Voltages Referenced to GND)

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Guaranteed Limit						Unit	
				25°C			-40 to 85°C		-55 to 125°C		
				Min	Typ	Max	Min	Max	Min		Max
V <sub>IH</sub>	Minimum High-Level Input Voltage, Channel-Select or Enable Inputs		2.0	1.5			1.5			1.5	V
			3.0	2.1			2.1			2.1	
			4.5	3.15			3.15			3.15	
			6.0	4.2			4.2			4.2	
V <sub>IL</sub>	Maximum Low-Level Input Voltage, Channel-Select or Enable Inputs		2.0			0.5		0.5		0.5	V
			3.0			0.9		0.9		0.9	
			4.5			1.35		1.35		1.35	
			6.0			1.8		1.8		1.8	
I <sub>IN</sub>	Input Leakage Current, Control Inputs	V <sub>IN</sub> = V <sub>CC</sub> or GND	6.0			±0.1		±1.0		±1.0	μA
I <sub>CC</sub>	Maximum Supply Current per Package	V <sub>IN</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> =0 V <sub>IS</sub> = GND or V <sub>CC</sub> , V <sub>OS</sub> = V <sub>CC</sub> or GND	6.0			4.0		40		80	μA
R <sub>ON</sub>	ON Resistance	I <sub>O</sub> = 1 mA V <sub>IN</sub> = V <sub>CC</sub> or GND, V <sub>IS</sub> = V <sub>CC</sub> or GND	4.5		70	160		200		240	Ω
			6.0		60	140		175		210	
R <sub>ON(peak)</sub>	ON Resistance (peak)	I <sub>O</sub> = 1 mA V <sub>IN</sub> = V <sub>CC</sub> to GND, V <sub>IS</sub> = V <sub>CC</sub> to GND	4.5		90	180		225		270	Ω
			6.0		80	160		200		240	
ΔR <sub>on</sub>	ON Resistance Mismatch Between Any 2 Switches		4.5 6.0		10 8.5						Ω
I <sub>OFF</sub>	OFF-State Leakage Current, All Channels	SW OFF, V <sub>IS</sub> = V <sub>CC</sub> or GND	6.0			±0.8		±8		±8	μA
I <sub>ON</sub>	ON-State Leakage Current	SW OFF, V <sub>IS</sub> = V <sub>CC</sub> or GND	6.0			±0.8		±8		±8	μA

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## AC CHARACTERISTICS (INPUT $t_r, t_f = 6$ ns)

Symbol	Parameter	Conditions	$V_{CC}$ (V)	Guaranteed Limits						Unit	
				25°C			-40 to 85°C		-55 to 125°C		
				Min	Typ	Max	Min	Max	Min		Max
$t_{PLH},$ $t_{PHL}$	Propagation Delay Switch In to Out	$C_L = 50$ pF	2.0			75		95		110	ns
			4.5			15		19		22	
		$C_L = 15$ pF	5.0		6.0						
$t_{ON}$	Switch Turn-ON Time										ns
	$\bar{E}$ to Out	$C_L = 50$ pF	2.0			275		345		415	
			4.5			55		69		83	
			6.0			47		59		71	
	SN to Out	$C_L = 50$ pF	2.0			300		375		450	
4.5					60		75		90		
		$C_L = 15$ pF	5.0		23						
$t_{OFF}$	Switch Turn-OFF Time										ns
	$\bar{E}$ to Out	$C_L = 50$ pF	2.0			275		345		415	
			4.5			55		69		83	
			6.0			47		59		71	
	SN to Out	$C_L = 50$ pF	2.0			290		365		435	
4.5					58		73		87		
		$C_L = 15$ pF	5.0		21						
$C_{in}$	Input Capacitance, Control Pins				3.5	10		10		10	pF
$C_{PD}$	Power Dissipation Capacitance (Note 4)	$C_L = 15$ pF	5.0			29					pF

4.  $C_{PD}$  is used to determine the dynamic power consumption, per multivibrator.

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## ANALOG SWITCH CHANNEL CHARACTERISTICS

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Limit* 25°C	Unit
BW	Maximum On-Channel Bandwidth or Minimum Frequency Response	f <sub>in</sub> = 1 MHz Sine Wave Adjust f <sub>in</sub> Voltage to Obtain 0 dBm at V <sub>OS</sub> Increase f <sub>in</sub> Frequency Until dB Meter Reads - 3 dB R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 10 pF	4.5	90	MHz
-	Off-Channel Feedthrough Isolation	f <sub>in</sub> ≡ Sine Wave Adjust f <sub>in</sub> Voltage to Obtain 0 dBm at V <sub>IS</sub> f <sub>in</sub> = 10 kHz, R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF f <sub>in</sub> = 1.0 MHz, R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 10 pF	4.5 4.5	-65 -75	dB
-	Feedthrough Noise E <sub>1</sub> , Sn to Switch	V <sub>in</sub> ≤ 1 MHz Square Wave (t <sub>r</sub> = t <sub>f</sub> = 6 ns) Adjust R <sub>L</sub> at Setup so that I <sub>S</sub> = 0 A R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 10 pF	4.5 4.5	60 30	mV <sub>PP</sub>
-	Crosstalk Between Any Two Switches	f <sub>in</sub> ≡ Sine Wave Adjust f <sub>in</sub> Voltage to Obtain 0 dBm at V <sub>IS</sub> f <sub>in</sub> = 10 kHz, R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF f <sub>in</sub> = 1.0 MHz, R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 10 pF	4.5 4.5	-70 -80	dB
THD	Total Harmonic Distortion	f <sub>in</sub> = 1 kHz, R <sub>L</sub> = 10 kΩ, C <sub>L</sub> = 50 pF THD = THD <sub>Measured</sub> - THD <sub>Source</sub> V <sub>IS</sub> = 4.0 V <sub>PP</sub> sine wave	4.5	0.04	%
C <sub>S</sub>	Switch Input Capacitance			5	pF
C <sub>COM</sub>	Switch Common Capacitance			45	pF

\*Limits not tested. Determined by design and verified by qualification.

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## TYPICAL CHARACTERISTICS

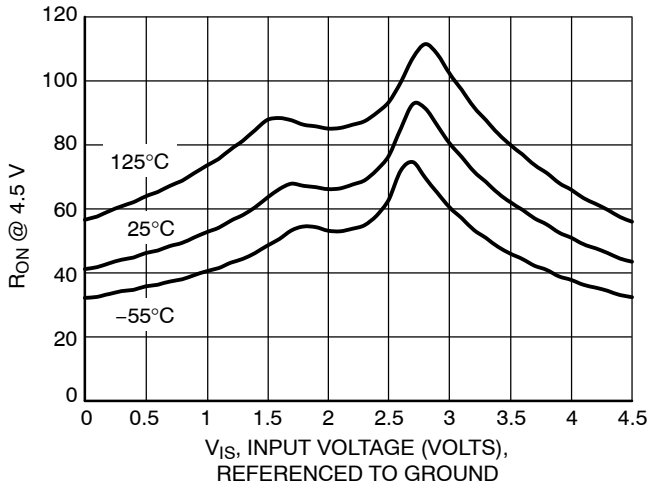


Figure 3. Typical On Resistance,  $V_{CC} = 4.5 \text{ V}$

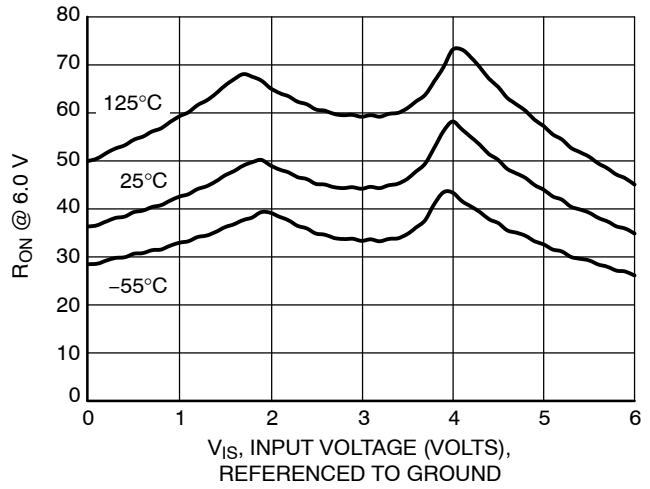


Figure 4. Typical On Resistance,  $V_{CC} = 6.0 \text{ V}$

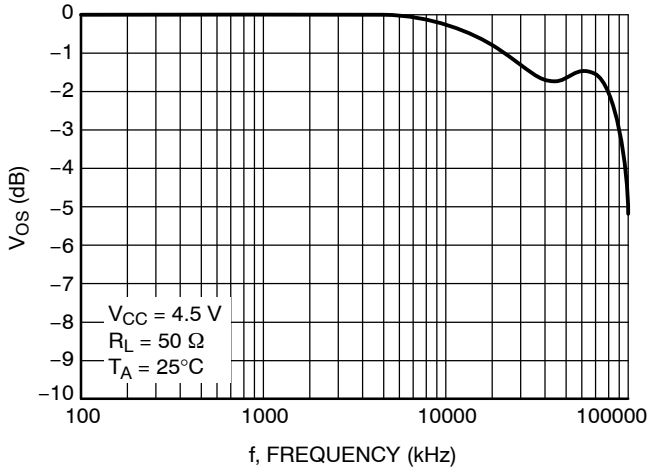


Figure 5. Typical Switch Frequency Response

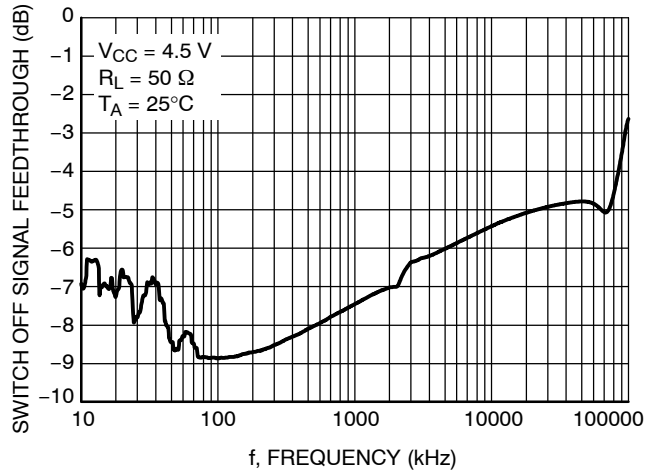


Figure 6. Typical Switch OFF Signal Feedthrough vs Frequency

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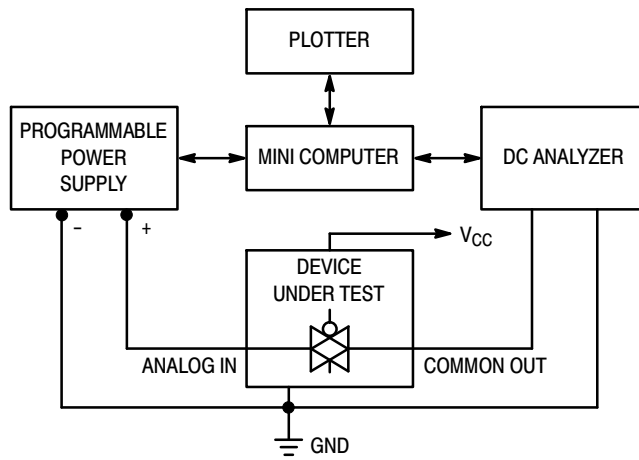


Figure 7. On Resistance Test Setup

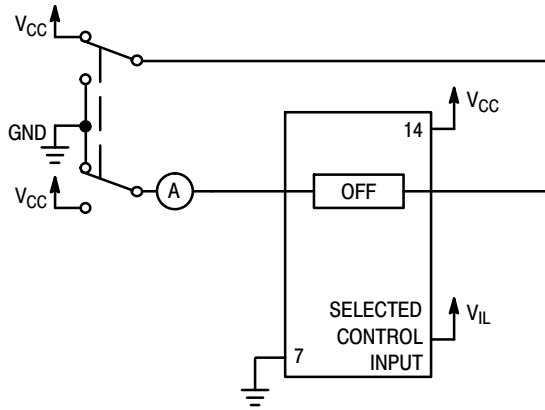


Figure 8. OFF Channel Leakage Current Test Setup, Any One Channel

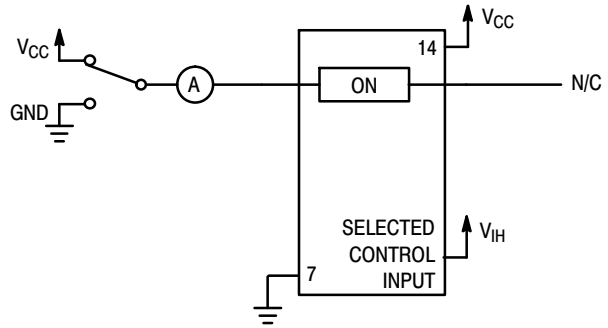


Figure 9. ON Channel Leakage Current Test Setup

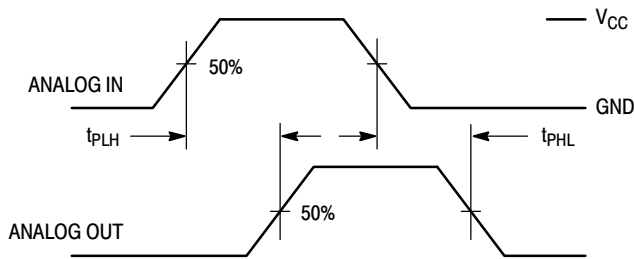
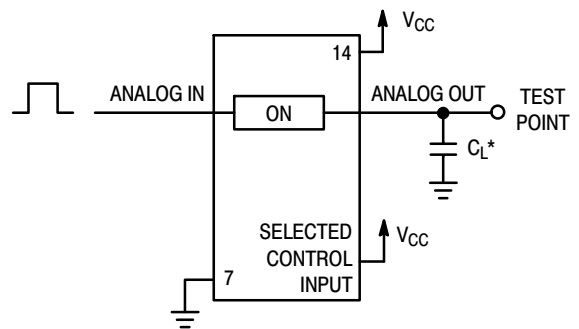


Figure 10. Propagation Delay, Analog In to Analog Out



\*Includes all probe and jig capacitance.

Figure 11. Propagation Delay Test Setup



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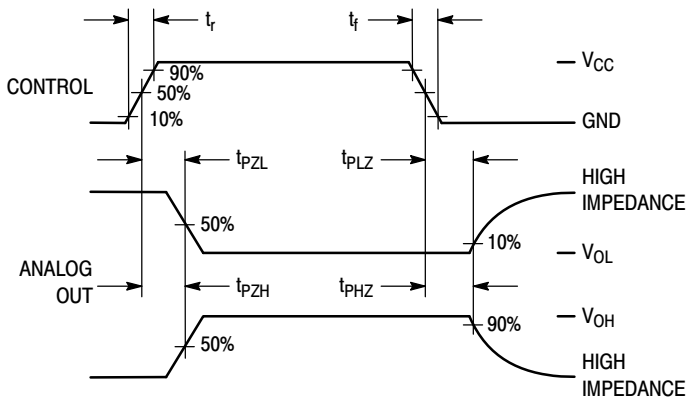
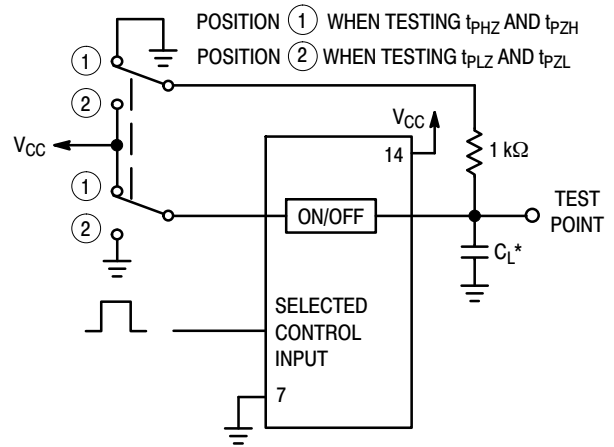


Figure 12. Turn-ON / Turn-OFF Times



\*Includes all probe and jig capacitance.

Figure 13. Turn-ON / Turn-OFF Time Test Setup

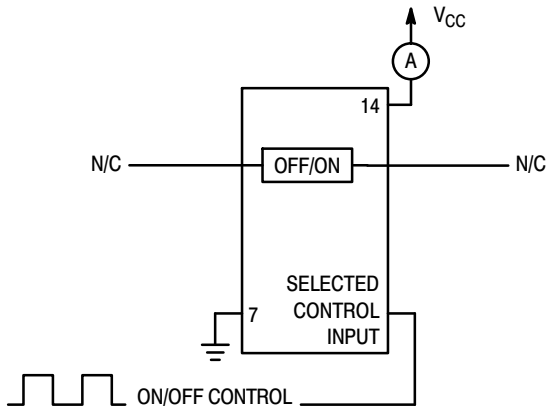
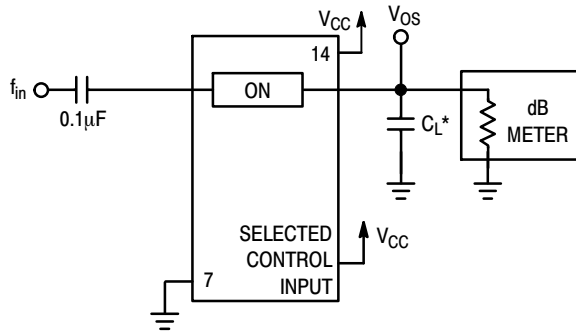
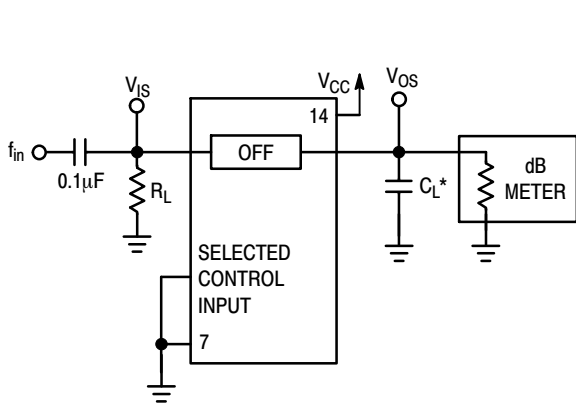


Figure 14. Power Dissipation Capacitance Test Setup



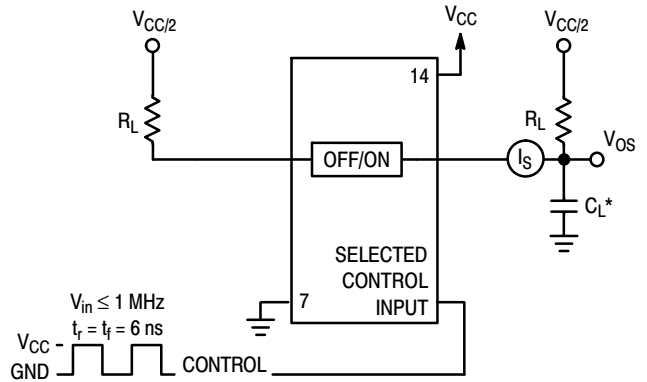
\*Includes all probe and jig capacitance.

Figure 15. ON Channel Bandwidth Test Setup



\*Includes all probe and jig capacitance.

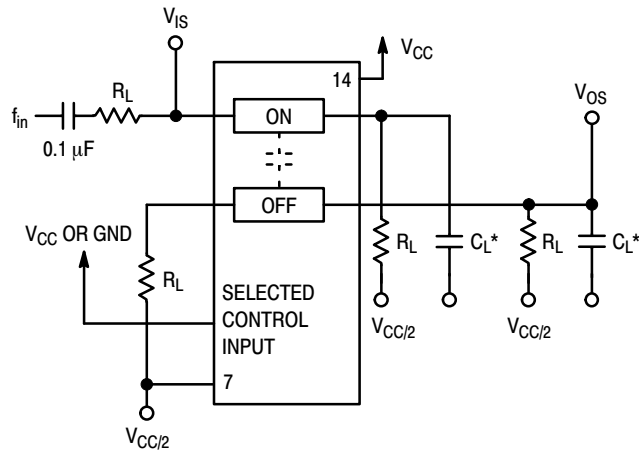
Figure 16. OFF Channel Feedthrough Isolation Test Setup



\*Includes all probe and jig capacitance.

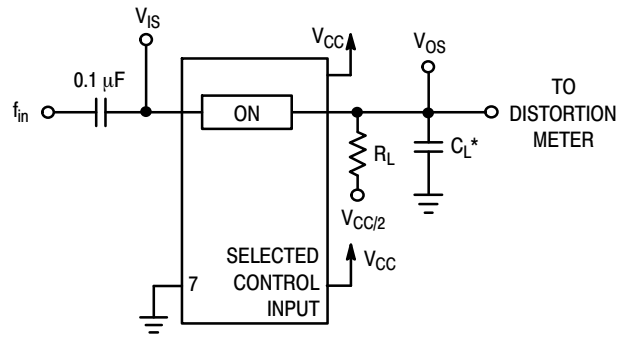
Figure 17. Feedthrough Noise Test Setup

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\*Includes all probe and jig capacitance.

**Figure 18. Crosstalk Between Any Two Switches Test Setup**



\*Includes all probe and jig capacitance.

**Figure 19. Total Harmonic Distortion Test Setup**

## ORDERING INFORMATION

Device	Package	Shipping†
MC74HC4067ADWR2G	SOIC-24 (Pb-Free)	1000 / Tape & Reel
MC74HC4067ADTR2G	TSSOP-24*	2500 / Tape & Reel

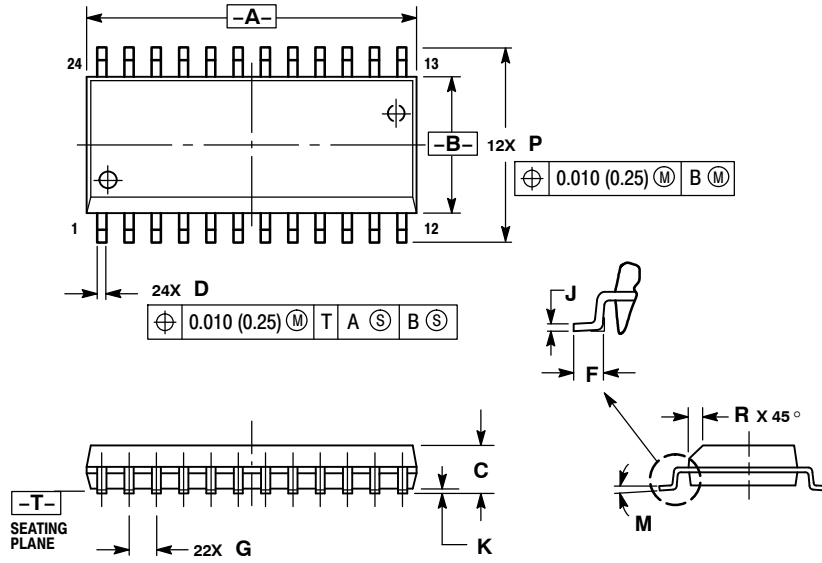
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*This package is inherently Pb-Free.

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## PACKAGE DIMENSIONS

SOIC-24  
CASE 751E-04  
ISSUE E



**NOTES:**

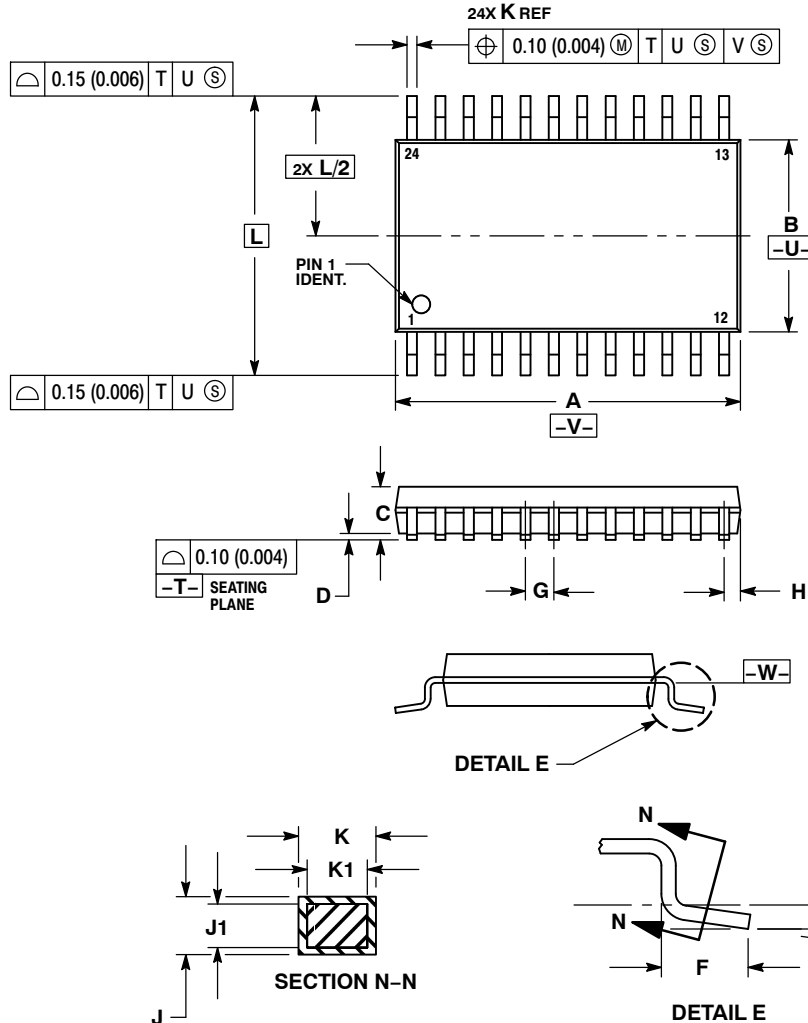
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	15.25	15.54	0.601	0.612
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27 BSC		0.050 BSC	
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0°	8°	0°	8°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

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## PACKAGE DIMENSIONS

TSSOP-24  
CASE 948H-01  
ISSUE A



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	7.70	7.90	0.303	0.311
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.27	0.37	0.011	0.015
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

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Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

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